

Product specification

1997 Sep 16



### PDIUSBP11

#### **FEATURES**

- Utilizes digital inputs and outputs to transmit and receive USB cable data
- Supports 12Mbit/s "Full Speed" and 1.5Mbit/s "Low Speed" serial data transmission
- Compatible with the VHDL "Serial Interface Engine" from USB developer's conference
- Available in SO, 14 pin package
- Hysteresis on D+, D–, V<sub>MO</sub> inputs

#### DESCRIPTION

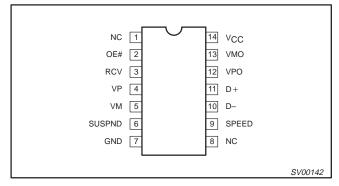
The PDIUSBP11 is a one chip generic USB transceiver. It is designed to allow 5.0V or 3.3V programmable and standard logic to interface with the physical layer of the Universal Serial Bus. It is capable of transmitting and receiving serial data at both full speed (12Mbit/s) and low speed (1.5Mbit/s) data rates. The outputs from the serial interface engine (inputs VPO and VMO on the PDIUSBP11) are driven by the host. The gated inputs (outputs VP and VM on the PDIUSBP11) are to be decoded by the host.

Implementation of the Serial Interface Engine along with the USB transceiver allow the designer to make flexible USB compatible devices with widely available logic components.

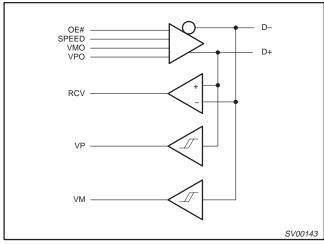
#### **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
14-pin plastic SO	0°C to +70°C	PDIUSBP11 D	PDIUSBP11 D	SOT108-1
14-pin plastic SSOP	0°C to +70°C	PDIUSBP11 DB	PDIUSBP11 DB	SOT337-1
14-pin plastic TSSOP	0°C to +70°C	PDIUSBP11 PW	PDUSBP11 PW DH	SOT402-1

#### **PIN CONFIGURATION**



#### **FUNCTIONAL DIAGRAM**



#### **PIN DESCRIPTION**

PIN No.	PIN SYMBOL	I/O	NAME AND FUNCTION				
3	RCV	0	Receive data. CMOS level output for USB differential input				
2	OE#	I	Output Enable. Active LOW, enables the transceiver to transmit data on the bus. When not active the transceiver is in receive mode				
			Inputs to from SIE		tial driver. (Outputs		
			VPO	VMO	RESULT		
12, 13	VPO, VMO	I	0	0	SE0		
	VIVIO		0	1	Logic "0"		
			1	0	Logic "1"		
			1	1	Undefined		
4, 5	VP, VM	0	are logio detect s error co	c "0" and ingle end	D- and D+. Outputs logic "1". Used to led zero (SEO#), and interconnect SIE). <b>RESULT</b> SE0 Low Speed Full Speed Error		
11, 10	D+, D–	I/O	Data+, Data–. Differential data bus conforming to the Universal Serial Bus standard.				
6	SUSPND	I	Suspend. Enables a low power state while the USB bus is inactive. While the suspnd pin is active it will drive the RCV pin to a logic "0" state.				
9	SPEED	I	Edge rate control. Logic "1" operates at edge rates for "full speed". Logic "0" operates edge rates for "low speed".				
			0.014	0.01/			
14	V <sub>CC</sub>		3.0V to 3.6V power supply				

## PDIUSBP11

#### **RECOMMENDED OPERATING CONDITIONS**

SYMDOL	DADAMETED	CONDITIONS	LIM	UNIT	
STWBOL	SYMBOL PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CC</sub>	DC supply voltage		3.0	3.6	V
VI	DC Input voltage range		0	5.5	V
V <sub>I/O</sub>	DC input range for I/O's		0	V <sub>CC</sub>	V
Vo	DC output voltage range		0	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating ambient temperature range in free air	See DC and AC characteristics for individual device	0	+70	°C

#### **ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

	DADAMETED		LIMITS		
SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5	+6.5	V
I <sub>IK</sub>	DC input diode current	V <sub>1</sub> < 0	-	-50	mA
VI	DC input voltage	Note 3	-0.5	+5.5	V
V <sub>I/O</sub>	DC input voltage range for I/O's		-0.5	V <sub>CC</sub> +0.5	V
I <sub>OK</sub>	DC output diode current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0	-	±50	mA
V <sub>O</sub>	DC output voltage	Note 3	-0.5	V <sub>CC</sub> +0.5	V
Ι <sub>Ο</sub>	DC output source or sink current for VP/VM, RCV pins	$V_{O} = 0$ to $V_{CC}$	-	±15	mA
Ι <sub>Ο</sub>	DC output source or sink current for D+/D- pins	$V_{O} = 0$ to $V_{CC}$	-	±50	mA
I <sub>GND</sub> , I <sub>CC</sub>	DC V <sub>CC</sub> or GND current		-	±100	mA
T <sub>stg</sub>	Storage temperature range		-60	+150	°C
P <sub>tot</sub>	Power dissipation per package				mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
The input and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.

### PDIUSBP11

#### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions Voltages are referenced to  $\vec{GND}$  (ground = 0V)

			LIMITS Temp = 0°C to +70°C			UNIT	
SYMBOL	PARAMETER	TEST CONDITIONS					
			MIN	TYP <sup>1</sup>	MAX	1	
VIH	HIGH level input	$V_{CC} = 3.0V \text{ to } 3.6V^3$	2.0			V	
V <sub>IL</sub>	LOW level input	$V_{CC} = 3.0 V \text{ to } 3.6 V^3$			0.8	V	
R <sub>D</sub> H	Output impedance (HIGH state)	Note 2	28	34	43	Ω	
R <sub>D</sub> L	Output impedance (LOW state)	Note 2	28	35	51	Ω	
V <sub>OH</sub> HIGH level output <sup>3</sup>		$V_{CC} = 3.0V; I_{O} = 6mA$	2.2	2.7			
	HIGH level output <sup>3</sup>	$V_{CC} = 3.0V; I_{O} = 4mA$	2.4			V	
		V <sub>CC</sub> = 3.0V; I <sub>O</sub> = 100µA	2.8	- 1			
		$V_{CC} = 3.0V; I_{O} = 6mA$		0.3	0.8		
V <sub>OL</sub>	LOW level output <sup>3</sup>	$V_{CC} = 3.0V; I_{O} = 4mA$			0.5	V	
		V <sub>CC</sub> = 3.0V; I <sub>O</sub> = 100µA		-	0.2	2	
Iccq	Quiescent supply current	$V_{CC} = 3.6V$ ; $V_I = V_{CC}$ or GND; $I_O = 0$		330	600	μA	
I <sub>CCS</sub>	Supply current in Suspend	$V_{CC} = 3.6V; V_{I} = V_{CC} \text{ or GND}; I_{O} = 0$		-	65	μA	
I <sub>CCFS</sub>	Active supply current (Full Speed)	$V_{CC} = 3.3V$		10	30	mA	
I <sub>CCLS</sub>	Active supply current (Low Speed)	$V_{CC} = 3.3V$		2	25	mA	
l <sub>l</sub>	Input leakage current	$V_{CC}$ = 3.6V; $V_{I}$ = 5.5V or GND; not for I/O pins		±0.1	±5	μΑ	
I <sub>OZ</sub>	3-State output OFF-state current	$V_{I} = V_{IH}$ or $V_{IL}$ ; $V_{O} = V_{CC}$ or GND <sup>2</sup>			±10	μA	

NOTES:

1. All typical values are at  $V_{CC}$  = 3.3V and  $T_{amb}$  = 25°C. 2. This value includes an external resistor of 24 $\Omega$  ± 1%. See "Load D+ and D–" diagram for testing details.

3. All signals except D+ and D-.

#### **AC CHARACTERISTICS**

GND = 0V,  $t_R = t_F$  = 3.0ns,  $C_L$  = 50pF,  $R_L$  = 500 $\Omega$ ,  $V_{CC}$  = 3.3V

	PARAMETER	TEST CONDITIONS	WAVEFORMS	LIMITS					
SYMBOL				T <sub>amb</sub> = 25°C			$T_{amb} = 0^{\circ}C \text{ to } +70^{\circ}C$		
				MIN	TYP	MAX	MIN	MAX	
tp <sub>LH</sub>	VMO/VPO to D+/D-		1	0		12	0	15	ns
tp <sub>HL</sub>	Full Speed		1	0		12	0	15	115
t <sub>rise</sub>	Rise and Fall Times		2	4		20	4	20	ns
t <sub>fall</sub>	Full Speed		2	4		20	4	20	115
tp <sub>LH</sub>	VMO/VPO to D+/D-		1	30		300	30	300	
tp <sub>HL</sub>	Low Speed		1	30		300	30	300	ns
t <sub>rise</sub>	Rise and Fall Times Low Speed		2	75		300	75	300	ns
t <sub>fall</sub>				75		200	75	200	
tp <sub>LH</sub>	D+/D- to RCV		3			16		16	ns
tp <sub>HL</sub>			3			16		20	
tp <sub>LH</sub>	D+/D- to VP/VM		1			8		8	ns
tp <sub>HL</sub>						8		12	
tp <sub>HZ</sub>						12		12	ns
tp <sub>ZH</sub>	OE# to D+/D– RL = 500Ω		4			12		15	
tp <sub>LZ</sub>			4			10		10	
tp <sub>ZL</sub>	<u> </u>					10		15	
t <sub>su</sub>	Setup for SPEED		5	0					ns
V <sub>cr</sub>	Crossover point	Note 1	3	1.3		2.0	1.3	2.0	V

NOTE:

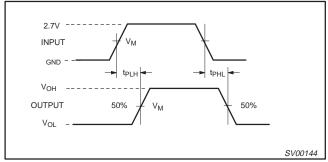
1. The crossover point is in the range of 1.3V to 2.5V for the low speed mode with a 50pF capacitance. In the low-speed mode with a 100pF or greater capacitance, the crossover point is in the range of 1.3V to 2.0V.

# PDIUSBP11

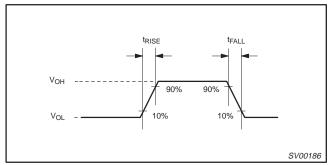
#### AC WAVEFORMS

 $V_{M} = 1.5V$   $V_{X} = V_{OL} + 0.3V$  $V_{Y} = V_{OH} - 0.3V$ 

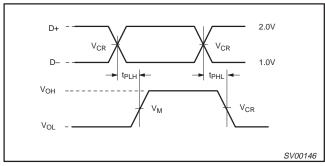
 $V_{OL}$  and  $V_{OH}$  are the typical output voltage drops that occur with the output load. (V\_{CC} never goes below 3.0V).



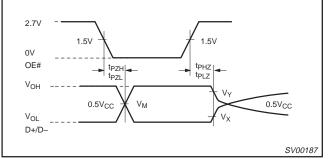
Waveform 1. D+/D- to VP/VM or VPO/VMO to D+/D-



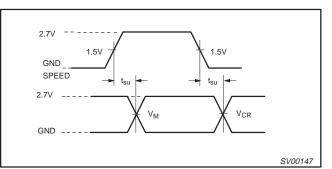
Waveform 2. Rise and Fall Times



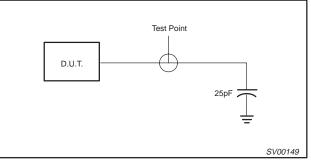
Waveform 3. D+/D- to RCV



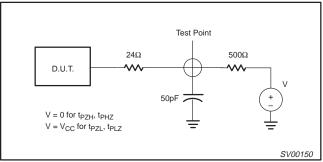
Waveform 4. OE# to D+/D-



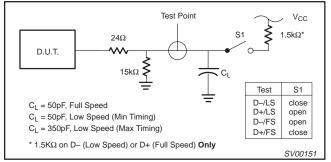
Waveform 5. Setup for Speed



Load for VM/VP and RCV

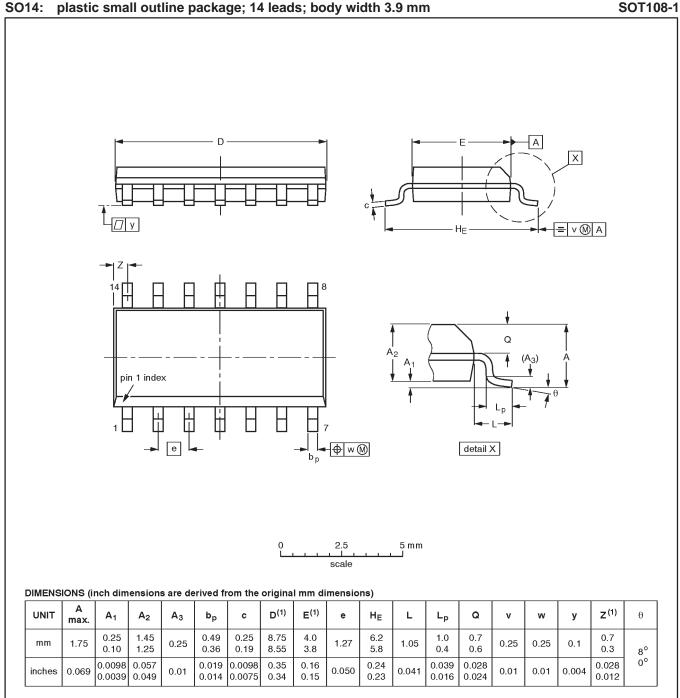


Load for Enable and Disable Times





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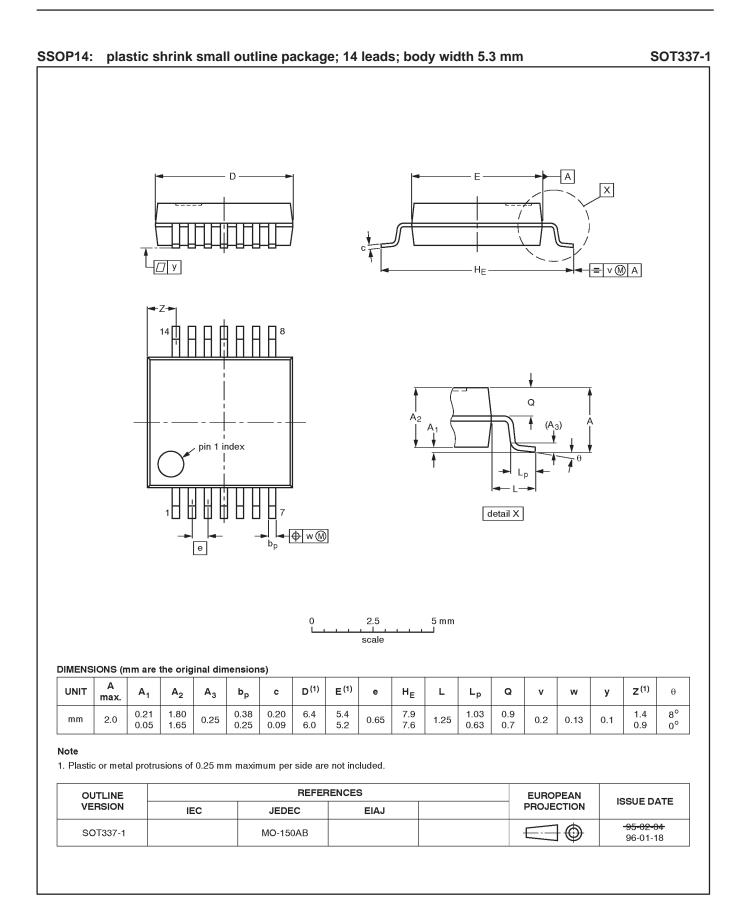


#### Note

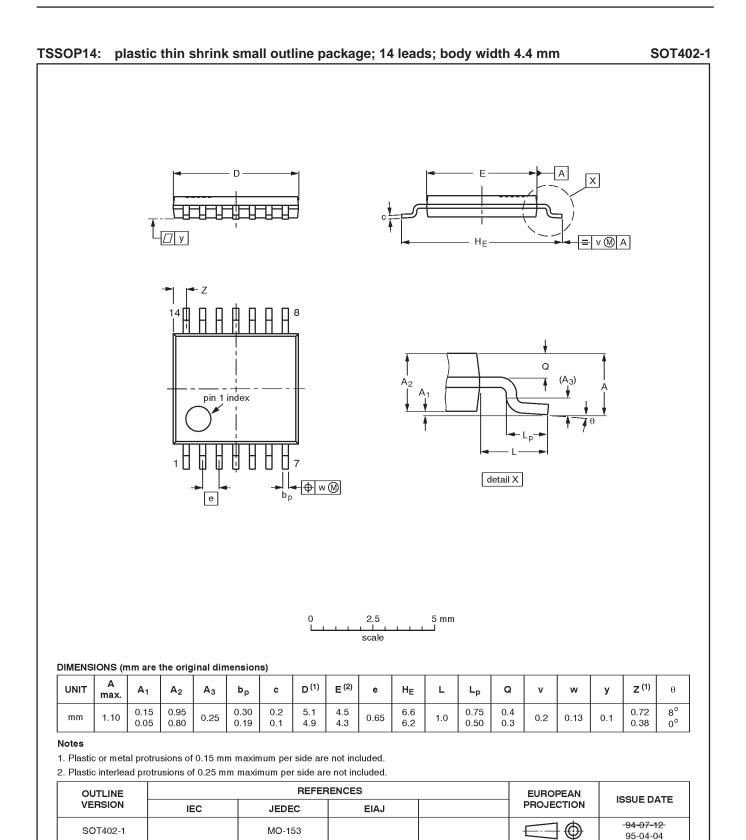
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT108-1	076E06S	MS-012AB				<del>91-08-13</del> 95-01-23

### PDIUSBP11



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NOTES

#### PDIUSBP11

	DEFINITIONS						
Data Sheet Identification     Product Status     Definition		Definition					
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.					
Preliminary Specification Preproduction Product		This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.					
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.					

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